

T496C225K035BT6110

T496 HRA, Tantalum, MnO₂ Tantalum, HRA, 2.2 uF, 10%, 35 VDC, SMD, MnO₂, Molded, Military, Fused, High Reliability, B (0.1%/1000 Hrs), 3.5 Ohms, 6032, 2.8 mm, 1.3 mm



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General Information

Series	T496 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Military, Fused, High Reliability
Features	Internal Fuse, High Reliability
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	224.48 mg

Specifications

Capacitance	2.2 uF
Tolerance	10%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	3500 mOhms (100kHz 25C)
Ripple Current	177 mA (rms, 100kHz 25C)
Leakage Current	0.8 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

Dimensions

L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
A	3.1mm MIN
B	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

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